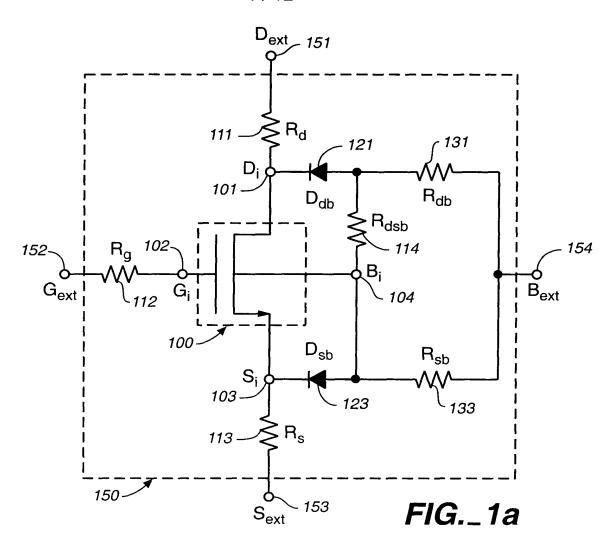
Title: MOSFET Modeling for IC Design . . .
Inventors: Zhang et al. Exp. Mail: EV 321716094 US
Filing Date: Herewith Atty. Tel: (415) 318-1160 Sheet 1 of 12



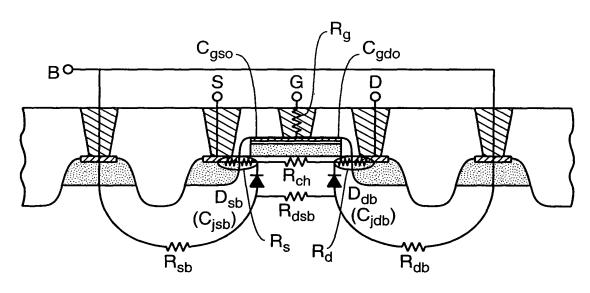


FIG._1b

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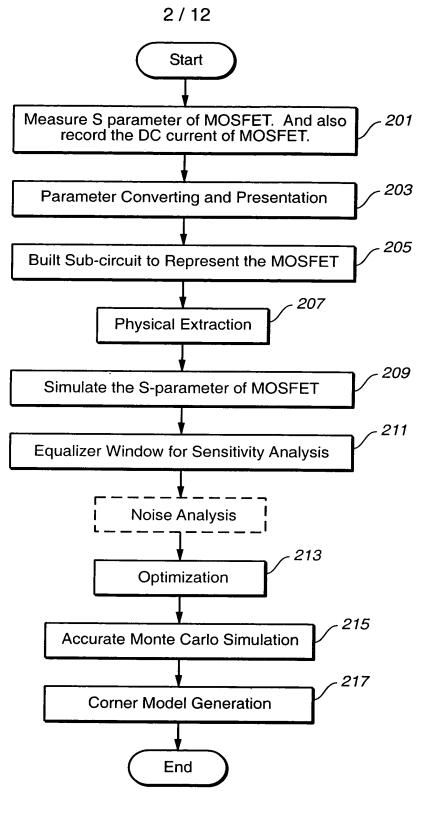


FIG._2

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Inventors: Zhang et al. Exp. Mail: EV 321716094 US
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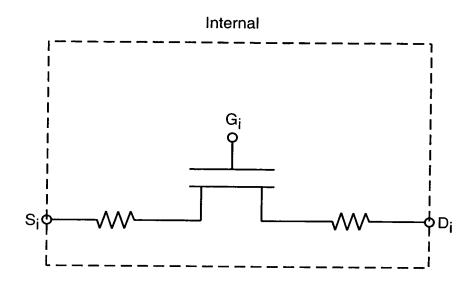


FIG._3a

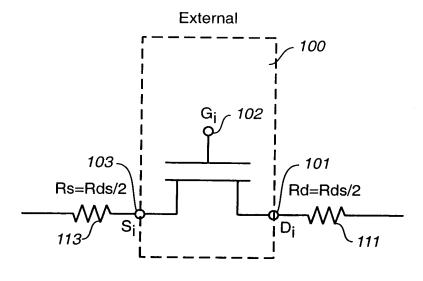
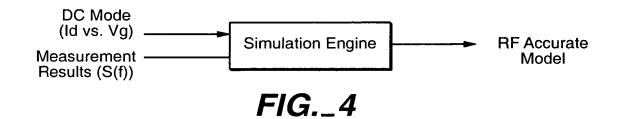
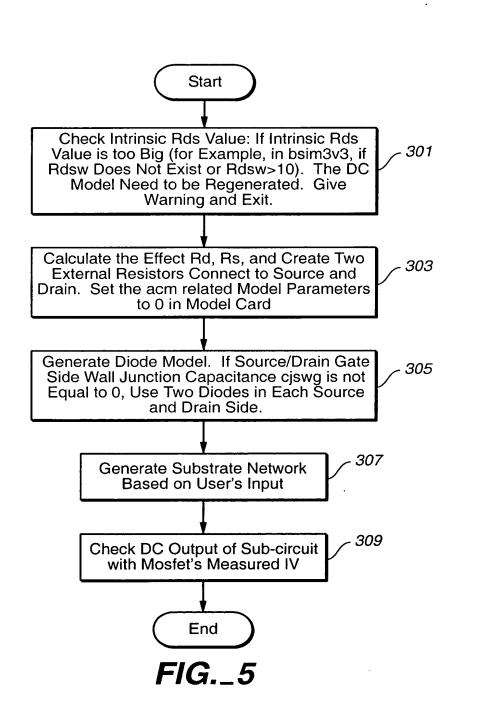
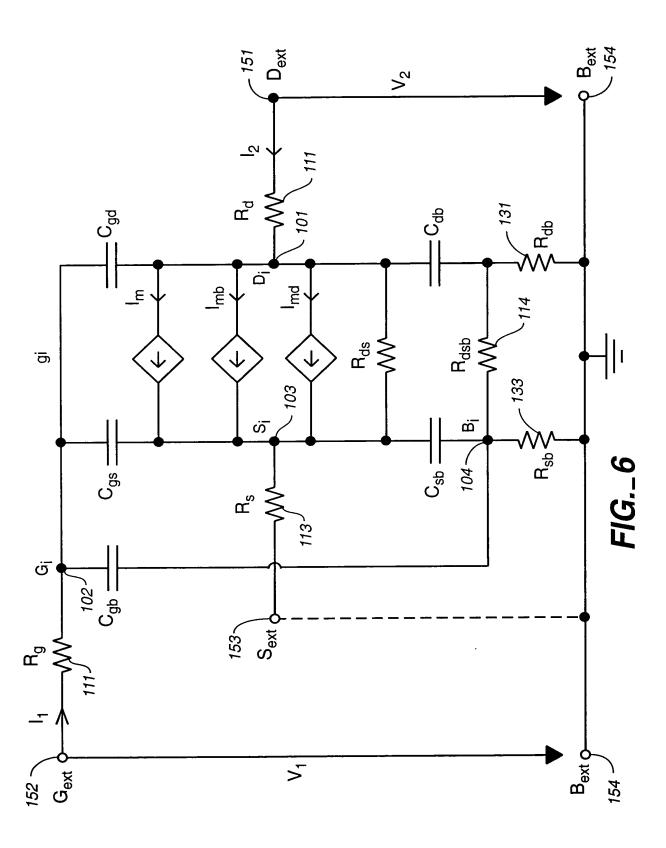


FIG._3b

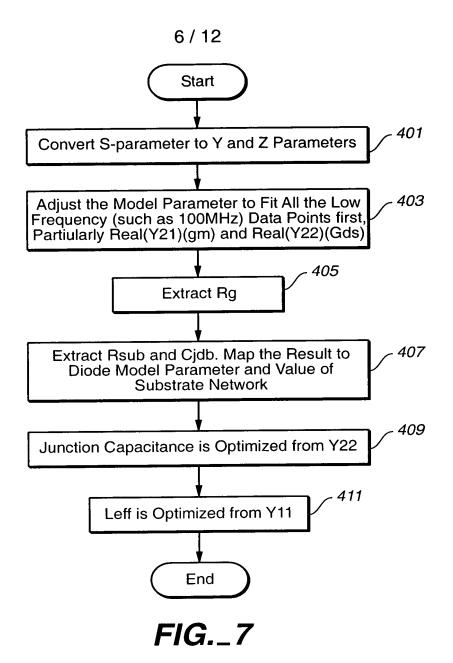




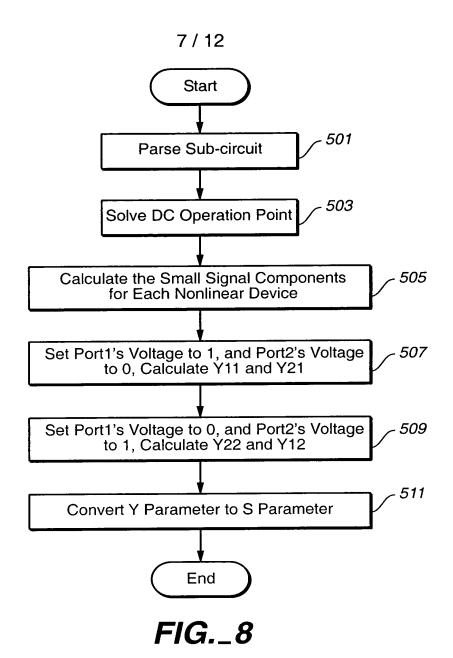
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Apple. No.: Unknown Docket No.: BTAT.001US1
Title: MOSFET Modeling for IC Design...
Inventors: Zhang et al. Exp. Mail: EV 321716094 US
Filing Date: Herewith Atty. Tel: (415) 318-1160 Sheet 6 of 12



Appln. No.: Unknown Docket No.: BTAT.001US1
Title: MOSFET Modeling for IC Design . . .
Inventors: Zhang et al. Exp. Mail: EV 321716094 US
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Title: MOSFET Modeling for IC Design . . .
Inventors: Zhang et al. Exp. Mail: EV 321716094 US
Filing Date: Herewith Atty. Tel: (415) 318-1160 Sheet 8 of 12

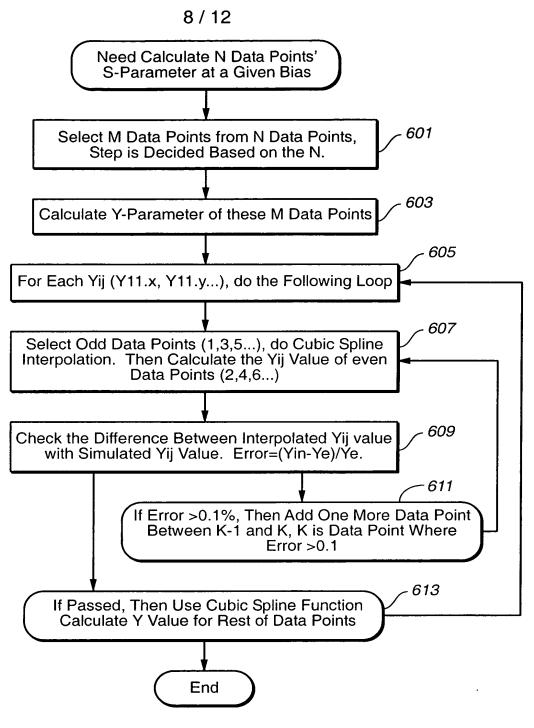


FIG._9

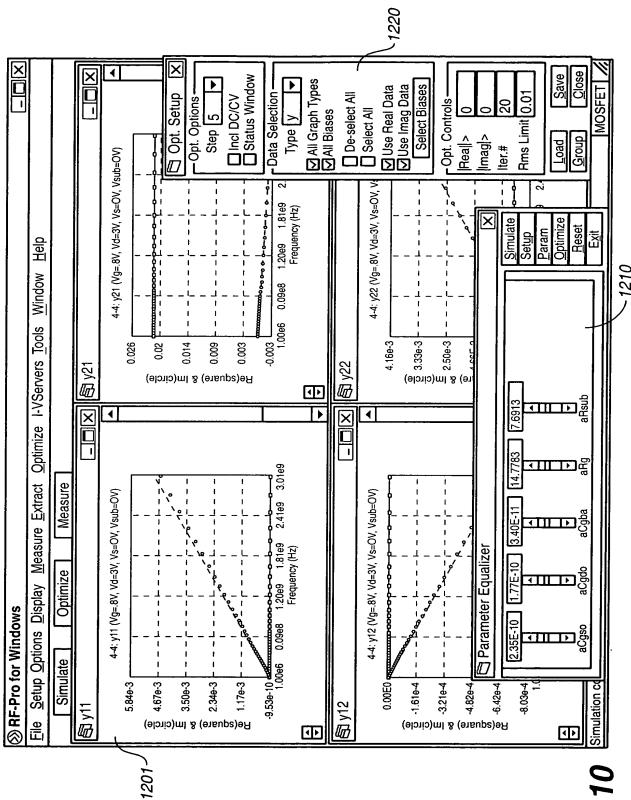


FIG._ 10

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Inventors: Zhang et al. Exp. Mail: EV 321716094 US
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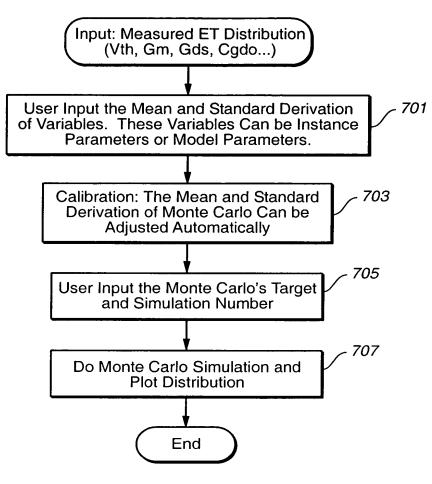
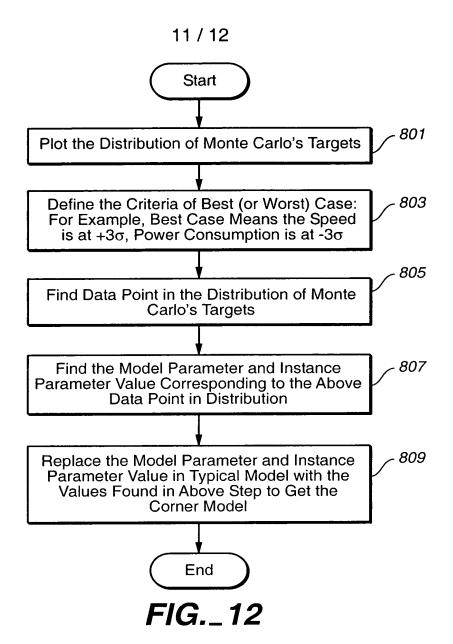


FIG._11

Appin. No. Unknown Docket No. B1A1.0010S1
Title: MOSFET Modeling for IC Design . . .
Inventors: Zhang et al. Exp. Mail: EV 321716094 US
Filing Date: Herewith Atty. Tel: (415) 318-1160 Sheet 11 of 12



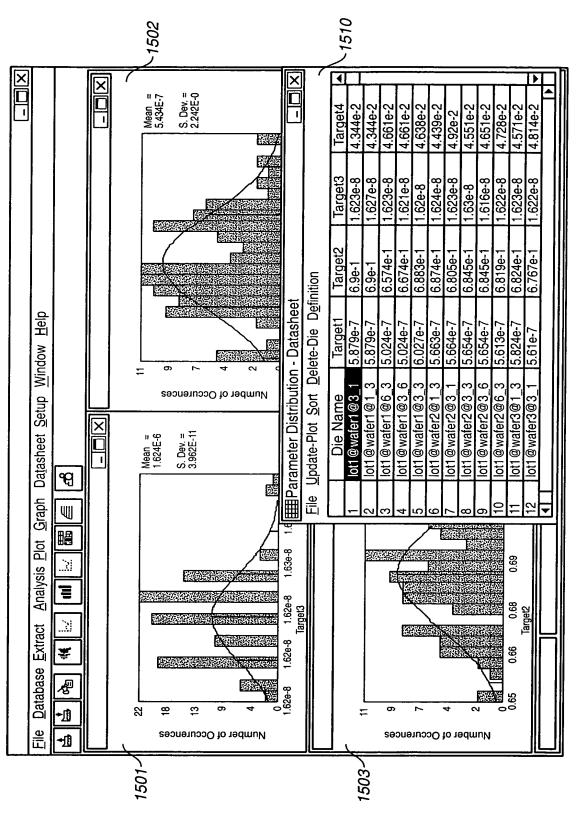


FIG._ 13